Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8127

Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: $R_{DS}(ON) = 5 m\Omega$ (typ.)
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -0.5mA)

Characte	ristics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	-30	V	
Drain-gate voltage (R	t _{GS} = 20 kΩ)	V _{DGR}	-30	V	
Gate-source voltage		V _{GSS}	-25/+20	V	
Drain current	DC (Note 1)	ID	-13	Α	
Drain current	Pulse (Note 1)	I _{DP}	-52	A	
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	1.9	W	
Drain power dissipati	on (t = 10 s) (Note 2b)	PD	1.0	W	
Single pulse avalancl	ne energy (Note 3)	E _{AS}	110	mJ	
Avalanche current	(Note 1)	I _{AR}	-13	А	
Channel temperature		T _{ch}	150	°C	
Storage temperature	range	T _{stg}	-55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)

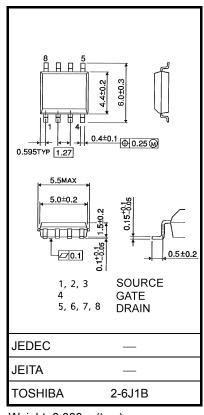
Note 1, Note 2, Note 3 : See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

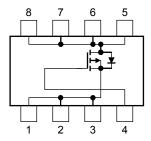
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

Circuit Configuration

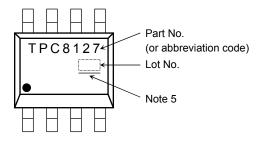


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Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

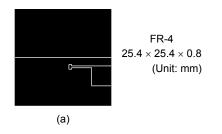
Marking (Note 4)

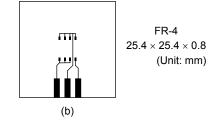


Note 1: Ensure that the channel temperature does not exceed 150 $^{\circ}\text{C}.$

Note 2: (a)Device mounted on a glass-epoxy board (a)

(b)Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD} = -24$ V, $T_{ch} = 25$ °C (initial), L =500 μ H, $R_G = 25 \Omega$, $I_{AR} = -13$ A

Note 4: • on lower left of the marking indicates Pin 1.

% Weekly code: (Three digits)



Week of manufacture _(01 for the first week of a year: sequential number up to 52 or 53) - Year of manufacture (The last digit of a year)

Note 5: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

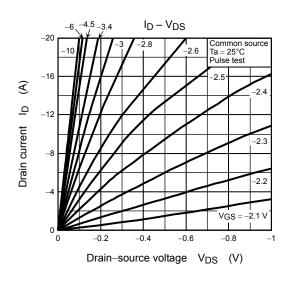
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage curre	ent	I _{GSS}	$V_{GS}=\pm 20~V,~V_{DS}=0~V$			±100	nA	
Drain cut-OFF curr	n cut-OFF current		$V_{DS} = -30$ V, $V_{GS} = 0$ V	_	_	-10	μA	
Drain agurag brag	kdown voltago	V (BR) DSS	$I_{D} = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30			v	
Dialii-source brea	e breakdown voltage		$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6)	-21	_	_	v	
Gate threshold voltage		V _{th}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.5 \text{ mA}$	-0.8		-2.0	V	
Drain-source ON-resistance		Pro (oti)	$V_{GS}=-4.5 \text{ V}, \text{ I}_{D}=-6.5 \text{ A}$	_	6.8	8.9	mΩ	
		R _{DS (ON)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6.5 \text{ A}$	_	5	6.5		
Input capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	3800	_	pF	
Reverse transfer capacitance		C _{rss}		_	620	_		
Output capacitance		C _{oss}		_	710	_		
Switching time	Rise time	tr	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$ $V_{GS} \stackrel{0}{\xrightarrow{-10}} V \stackrel{1}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{0}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{0}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{0}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{0}{\xrightarrow{-10}} \stackrel{1}{\xrightarrow{-10}} \stackrel{1}{-10$	_	9	_	• ns	
	Turn-ON time	t _{on}			17	_		
	Fall time	t _f			135	_		
	Turn-OFF time	t _{off}	$V_{DD}\approx -15~V$ Duty $\leq 1\%,~t_w=10~\mu s$	_	390	_		
Total gate charge (gate-source plus gate-drain)		Qg	V _{DD} ≈ -24 V, V _{GS} = -10 V,		92	—	nC	
Gate-source charge 1		Q _{gs1}	$I_{\rm D} = -13 \rm{A}$	—	10	—		
Gate-drain ("miller") charge		Q _{gd}		_	25	—		

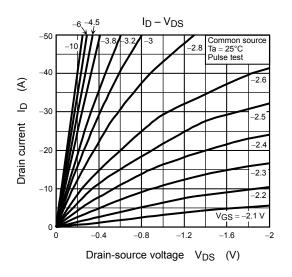
Source-Drain Ratings and Characteristics (Ta = 25°C)

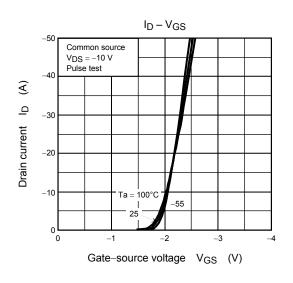
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	—	_	_	-52	А
Forward voltage (diode)		V _{DSF}	$I_{DR} = -13 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		_	1.2	V	

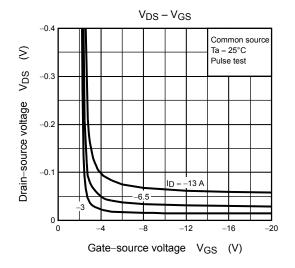
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

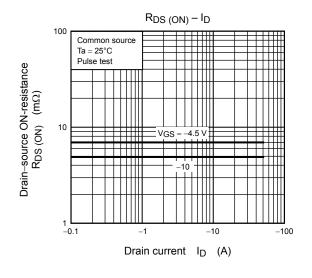
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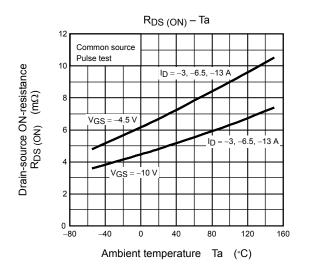


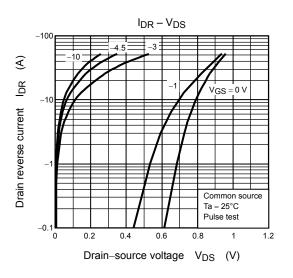


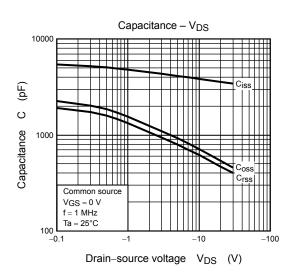


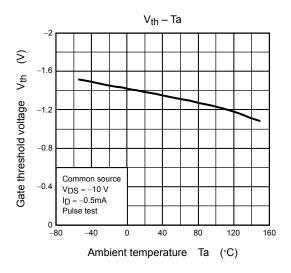


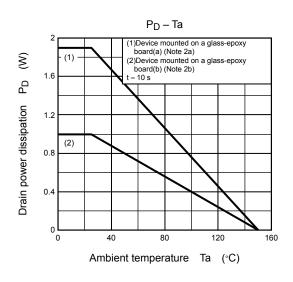
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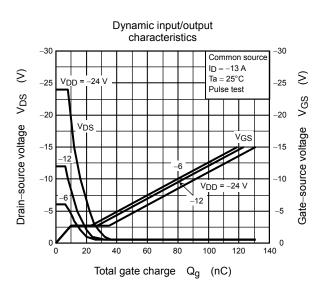


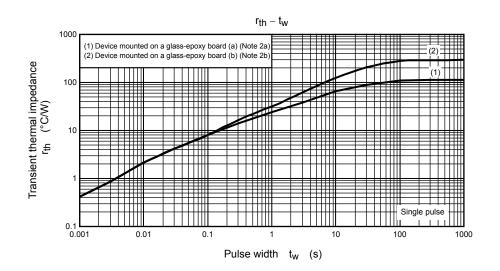


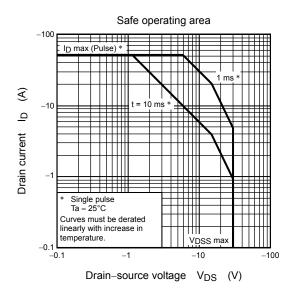












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